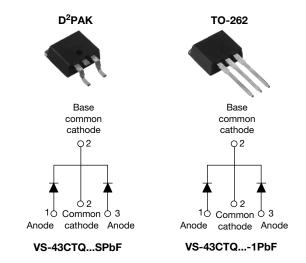


Vishay Semiconductors

Schottky Rectifier, 2 x 20 A



PRODUCT SUMMARY			
I _{F(AV)}	2 x 20 A		
V _R	80 V/100 V		

FEATURES

- 175 °C T_J operation
- Center tap configuration
- · Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Halogen-free according to IEC 61249-2-21 definition
- Compliant to RoHS Directive 2002/95/EC
- AEC-Q101 qualified

DESCRIPTION

This center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	40	А		
V _{RRM}		80/100	V		
I _{FSM}	t _p = 5 μs sine	850	А		
V _F	20 Apk, $T_J = 125 \ ^\circ C$ (per leg)	0.67	V		
TJ	Range	- 55 to 175	°C		

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-43CTQ080SPbF VS-43CTQ080-1PbF	VS-43CTQ100SPbF VS-43CTQ100-1PbF	UNITS	
Maximum DC reverse voltage	V _R	80	100	V	
Maximum working peak reverse voltage	V _{RWM}	80	100	v	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average per le	° .	$I_{F(AM)}$ 50 % duty cycle at T _C = 135 °C, rectangular waveform		20	
See fig. 5 per devi	e I _{F(AV)}	30% duty cycle at 10° = 135° C	, rectangular wavelonn	40 A	
Maximum peak one cycle non-repetitive surge current per leg		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	850	A
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	275	
Non-repetitive avalanche energy per leg	E _{AS}	$T_J = 25 \ ^{\circ}C, \ I_{AS} = 0.50 \ A, \ L = 60$) mH	7.50	mJ
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to ze Frequency limited by T _J maxim	•	0.50	A

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
		20 A	T.I = 25 °C	0.81	
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	40 A	1j=25 C	0.98	v
See fig. 1	VFM (1)	20 A	T 105 %C	0.67	
		40 A	T _J = 125 °C	0.81	
Maximum reverse leakage current per leg	I _{BM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	1	— mA
See fig. 2	IRM ('/	T _J = 125 °C	$v_{\rm R} = haleu v_{\rm R}$	11	
Threshold voltage	V _{F(TO)}			0.71	V
Forward slope resistance	r _t	$T_J = T_J maximum$		0.43	mΩ
Maximum junction capacitance per leg	CT	$V_R = 5 V_{DC}$ (test signal range	ge 100 kHz to 1 MHz), 25 °C	1480	pF
Typical series inductance per leg	L _S	Measured lead to lead 5 m	nm from package body	8.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

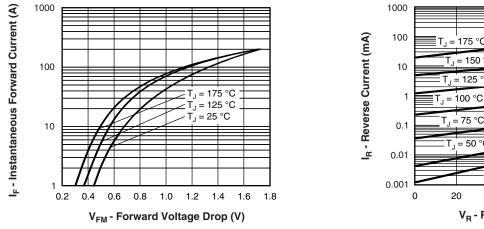
THERMAL - MECHAN	ICAL SP	ECIFICAT	IONS			
PARAMETER		SYMBOL	SYMBOL TEST CONDITIONS		UNITS	
Maximum junction and storage temperature range	•	T _J , T _{Stg}		- 55 to 175	°C	
Maximum thermal resistance, junction to case per leg		D		2.0		
Maximum thermal resistance, junction to case per package		R _{thJC}	DC operation	1.0	°C/W	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	greased 0.50		
Approximate weight				2	g	
Approximate weight				0.07	oz.	
Mounting torque	minimum			6 (5)	kgf ⋅ cm	
Mounting torque -	maximum			12 (10)	(lbf · in)	
			Case style D ² DAK	43CT0	2080S	
Maultine, alexies			Case style D ² PAK		2100S	
Marking device	Marking device		Case style TO 262	43CTC	2080-1	
			Case style TO-262		Q100-1	

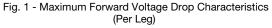
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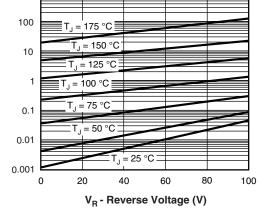


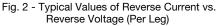
VS-43CTQ...SPbF, VS-43CTQ...-1PbF Series

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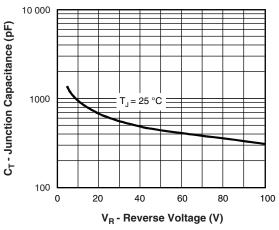


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

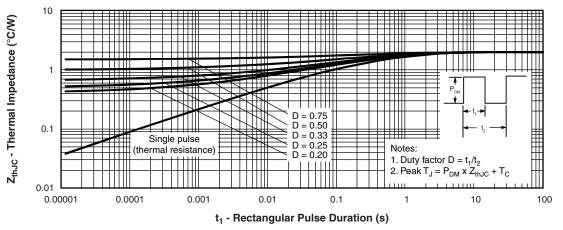


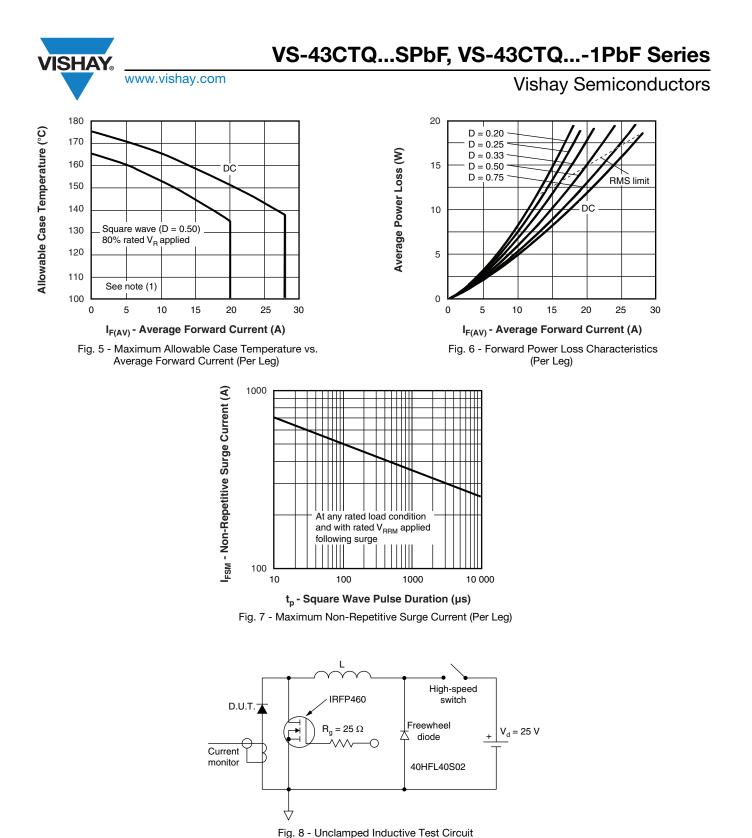
Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

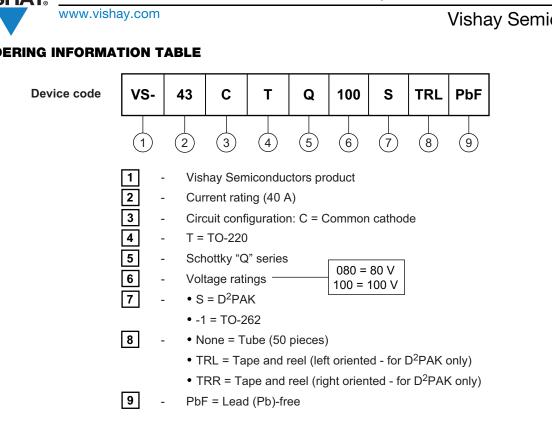
Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}/D$) (see fig. 6); Pd_{REV} = Inverse power loss = $V_{R1} \times I_R$ (1 - D); I_R at V_{R1} = 10 V

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Packaging information	www.vishay.com/doc?95032			
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VS-43CTQ...SPbF, VS-43CTQ...-1PbF Series

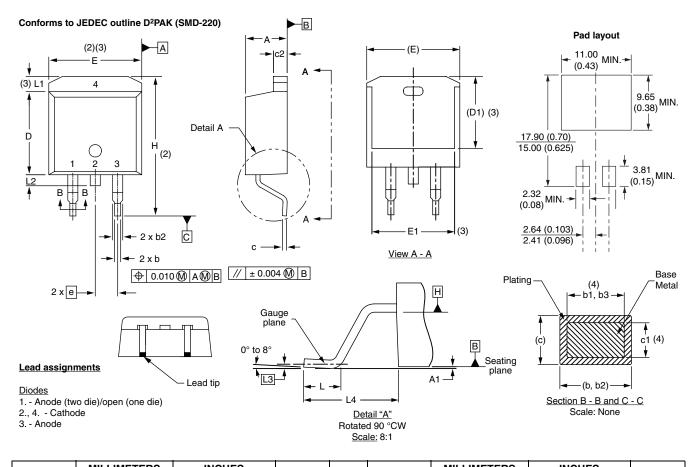
ORDERING INFORMATION TABLE

Vishay High Power Products

D²PAK, TO-262

DIMENSIONS FOR D²PAK in millimeters and inches

SHA



SYMBOL	MILLIM	ETERS	INC	HES	NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100	BSC	
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

⁽⁷⁾ Outline conforms to JEDEC outline TO-263AB

Notes

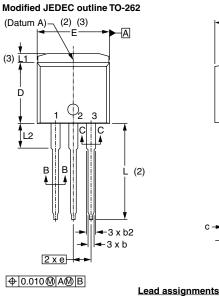
- ⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}\,$ Thermal pad contour optional within dimension E, L1, D1 and E1
- ⁽⁴⁾ Dimension b1 and c1 apply to base metal only
- ⁽⁵⁾ Datum A and B to be determined at datum plane H
- ⁽⁶⁾ Controlling dimension: inch

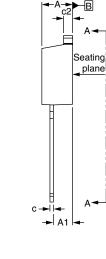
Vishay High Power Products

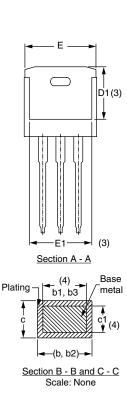
D²PAK, TO-262



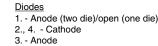
DIMENSIONS FOR TO-262 in millimeters and inches







Lead tip



SYMBOL	MILLIM	MILLIMETERS		INCHES		
	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	2.03	3.02	0.080	0.119		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	
D1	6.86	8.00	0.270	0.315	3	
E	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54 BSC		0.100	BSC		
L	13.46	14.10	0.530	0.555		
L1	-	1.65	-	0.065	3	
L2	3.56	3.71	0.140	0.146		

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- ⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Controlling dimension: inches

⁽⁶⁾ Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline

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